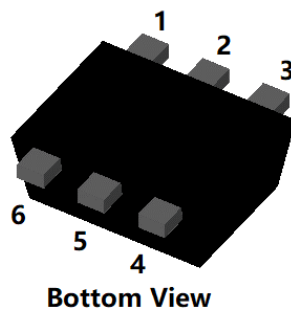
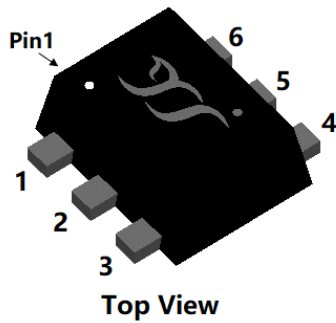
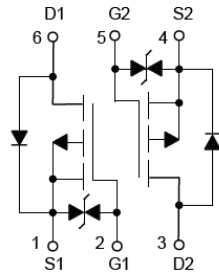


P-Channel Enhancement Mode Field Effect Transistor



SOT-563



Product Summary

- V_{DS} -20V
- I_D -0.5A
- $R_{DS(ON)}$ (at $V_{GS}=-4.5V$) < 850 mohm
- $R_{DS(ON)}$ (at $V_{GS}=-2.5V$) < 1200 mohm
- $R_{DS(ON)}$ (at $V_{GS}=-1.8V$) < 2000 mohm
- ESD Protected Up to 2.0KV (HBM)

General Description

- Trench Power LV MOSFET technology
- High Density Cell Design for Low $R_{DS(ON)}$
- High Speed switching

Applications

- Interfacing, Logic switch
- Load switch
- Power management

■ Absolute Maximum Ratings ($T_A=25^\circ C$ unless otherwise noted)

Parameter	Symbol	Maximum	Unit
Drain-source Voltage	V_{DS}	-20	V
Gate-source Voltage	V_{GS}	± 12	V
Drain Current	I_D	$T_A=25^\circ C$ Steady State	-0.5
		$T_A=70^\circ C$ Steady State	-0.4
Pulsed Drain Current ^A	I_{DM}	-2.6	A
Total Power Dissipation @ $T_A=25^\circ C$ Steady State	P_D	0.18	W
Thermal Resistance Junction-to-Ambient @ Steady State ^B	$R_{\theta JA}$	694	$^\circ C/W$
Junction and Storage Temperature Range	T_J, T_{STG}	-55~+150	$^\circ C$

■ Ordering Information (Example)

PREFERRED P/N	PACKING CODE	Marking	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
YJL3139KAX	F2	39A	3000	30000	120000	7" reel



YJL3139KAX

■ Electrical Characteristics (T_J=25°C unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Units
Static Parameter						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} = 0V, I _D =-250μA	-20			V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-20V, V _{GS} =0V, T _C =25°C			-1	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} = ±10V, V _{DS} =0V		±1.5	±10	μA
		V _{GS} = ±8V, V _{DS} =0V		±500	±2000	nA
Gate Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D =-250μA	-0.35	-0.62	-1.2	V
Static Drain-Source On-Resistance	R _{DS(on)}	V _{GS} = -4.5V, I _D =-0.5A		580	850	mΩ
		V _{GS} = -2.5V, I _D =-0.3A		855	1200	
		V _{GS} = -1.8V, I _D =-0.2A		1350	2000	
Diode Forward Voltage	V _{SD}	I _S =-0.5A, V _{GS} =0V		-0.8	-1.2	V
Maximum Body-Diode Continuous Current	I _S				-0.5	A
Dynamic Parameters						
Input Capacitance	C _{iss}	V _{DS} =-10V, V _{GS} =0V, f=1MHZ		71		pF
Output Capacitance	C _{oss}			20		
Reverse Transfer Capacitance	C _{rss}			15		
Switching Parameters						
Total Gate Charge	Q _g	V _{GS} =-4.5V, V _{DD} =-10V, I _D =-0.5A		1.24		nC
Gate Source Charge	Q _{gs}			0.37		
Gate Drain Charge	Q _{gd}			0.27		
Reverse Recovery Chrage	Q _{rr}	I _F =-0.5A, di/dt=-20A/us		0.97		
Reverse Recovery Time	t _{rr}			26		
Turn-on Delay Time	t _{D(on)}	V _{GS} =-4.5V, V _{DD} =-10V, R _L =2.5Ω, R _{GEN} =3Ω		4		ns
Turn-on Rise Time	t _r			19		
Turn-off Delay Time	t _{D(off)}			16		
Turn-off Fall Time	t _f			25		

A. Pulse Test: Pulse Width ≤ 300us, Duty cycle ≤ 2%.

B. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch.



■ Typical Performance Characteristics

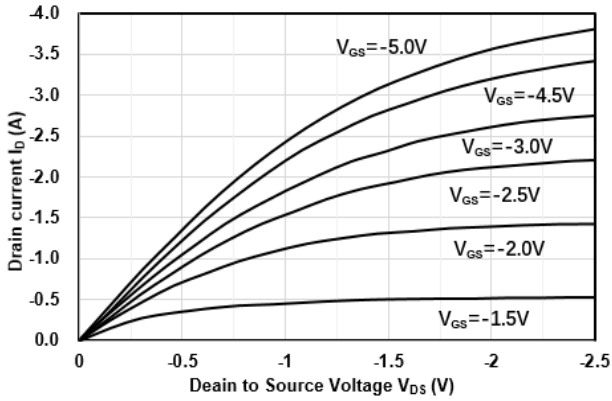


Figure1. Output Characteristics

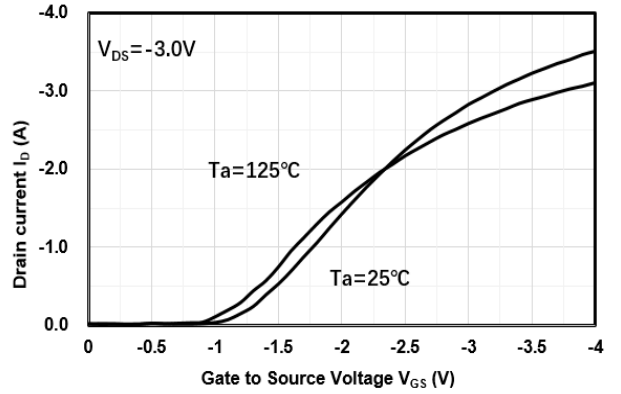


Figure2. Transfer Characteristics

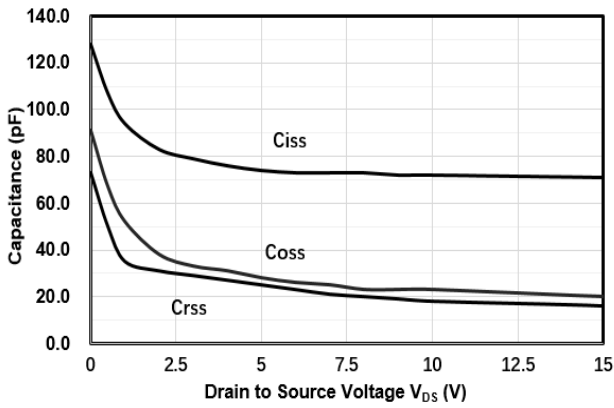


Figure3. Capacitance Characteristics

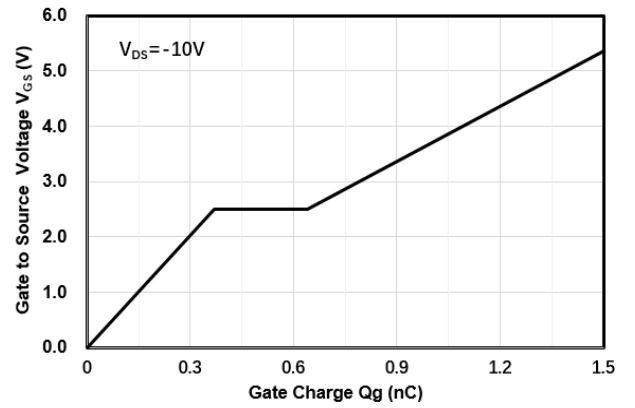


Figure4. Gate Charge

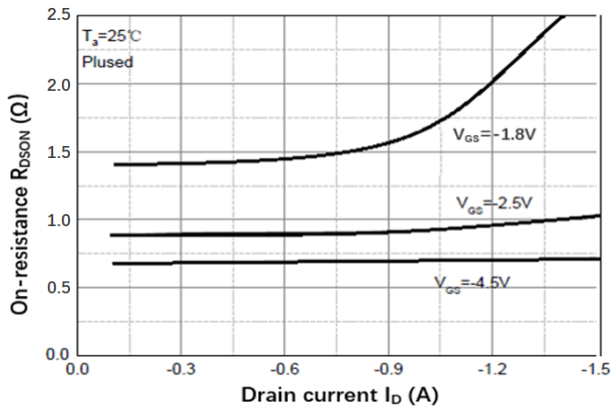


Figure5. Drain-Source on Resistance

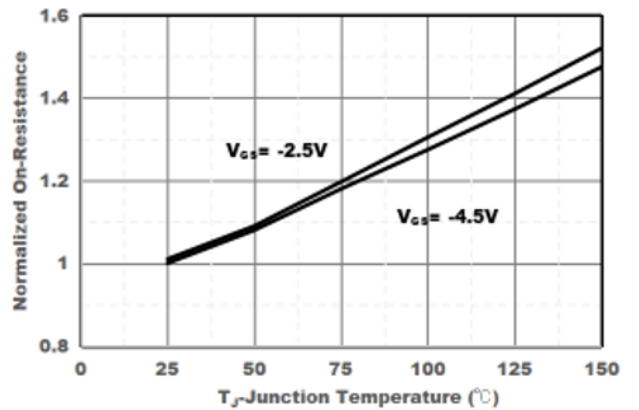
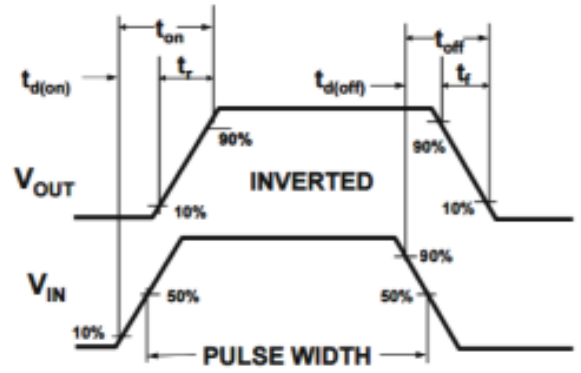
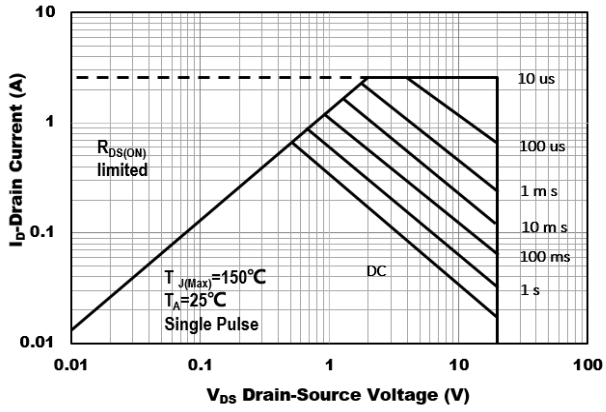


Figure6. Drain-Source on Resistance



YJL3139KAX

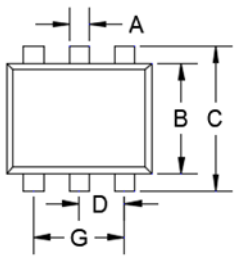




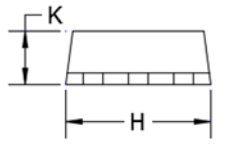
YJL3139KAX

■ SOT-563 Package information

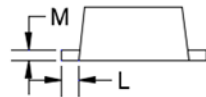
SOT-563



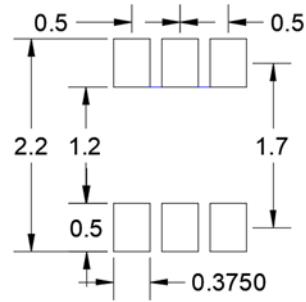
TOP VIEW



SIDE VIEW



SIDE VIEW



单位: mm

SUGGESTED SOLDER PAD LAYOUT

DIMENSIONS				
DIM	INCHES		MM	
	MIN	MAX	MIN	MAX
A	0.006	0.011	0.150	0.300
B	0.043	0.051	1.100	1.300
C	0.059	0.067	1.500	1.700
D	0.016	0.024	0.400	0.600
G	0.035	0.043	0.900	1.100
H	0.059	0.067	1.500	1.700
K	0.021	0.026	0.550	0.650
L	0.004	0.011	0.100	0.300
M	0.004	0.007	0.100	0.180



YJL3139KAX

Disclaimer

The information presented in this document is for reference only. Yangzhou Yangjie Electronic Technology Co., Ltd. reserves the right to make changes without notice for the specification of the products displayed herein to improve reliability, function or design or otherwise.

The product listed herein is designed to be used with ordinary electronic equipment or devices, and not designed to be used with equipment or devices which require high level of reliability and the malfunction of which would directly endanger human life (such as medical instruments, transportation equipment, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices), Yangjie or anyone on its behalf, assumes no responsibility or liability for any damages resulting from such improper use of sale.

This publication supersedes & replaces all information previously supplied. For additional information, please visit our website [http:// www.21yangjie.com](http://www.21yangjie.com) , or consult your nearest Yangjie's sales office for further assistance.



YJL3139KAX

REV.	EFFECTIVE DATE	REVISION HISTORY	PREPARED
1.0	2021.10.23	New release	Yanqiang He